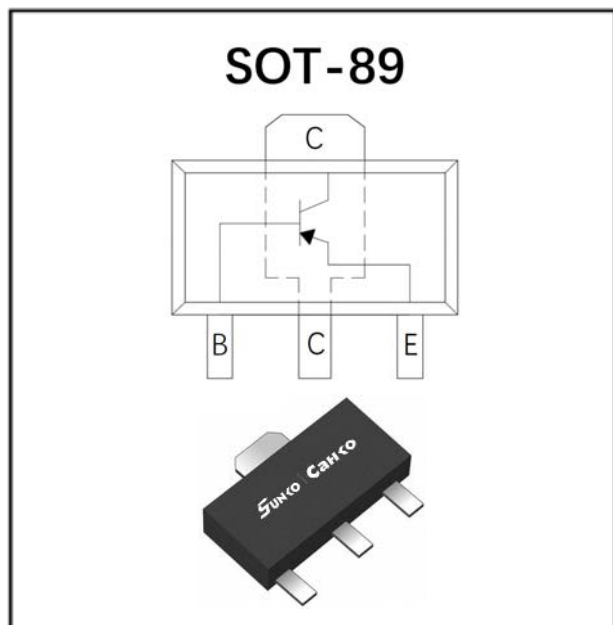


PNP General Purpose Amplifier



Features

- Epoxy meets UL-94 V-0 flammability rating
- Halogen free available upon request by adding suffix "HF"
- Moisture sensitivity level 1
- Low collector-emitter saturation voltage

Mechanical Data

- **Package:** SOT-89
- Molding compound meets UL 94 V-0 flammability rating, -compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Marking:**

2SB1188B-Q

BBCQ

■Maximum Ratings (Ta=25°C unless otherwise noted)

Item	Symbol	Unit	Conditions	Value
Minimum Collector-Emitter Voltage	V_{CEO}	V	$I_C = -1mA, I_B = 0$	-32
Minimum Collector-Base Voltage	V_{CBO}	V	$I_C = -50\mu A, I_E = 0$	-40
Minimum Emitter-Base Voltage	V_{EBO}	V	$I_E = -50\mu A, I_C = 0$	-5
Collector Current	I_C	A		-2
Collector Power Dissipation	P_C	mW		500
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	°C/W		250
Operation Junction Temperature	T_j	°C		-55 to +150
Storage Temperature	T_{stg}	°C		-55 to +150

2SB1188B

■Electrical Characteristics (Ta=25℃ unless otherwise noted)

Item	Symbol	Unit	Conditions	Min	TYP	Max
Collector-Emitter Voltage	V_{CEO}	V	$I_C=-1mA, I_B=0$	-32		
Collector-Base Voltage	V_{CBO}	V	$I_C=-50\mu A, I_E=0$	-40		
Emitter-Base Voltage	V_{EBO}	V	$I_E=-50\mu A, I_C=0$	-5		
Collector-Base cut-off current	I_{CBO}	μA	$V_{CB}=-20V$			-1
Emitter-Base cut-off current	I_{EBO}	μA	$V_{EB}=-4V$			-1
DC Current Gain	h_{FE}		$V_{CE}=-3V, I_C=-500mA$	120		270
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V	$I_C=-2A, I_B=-200mA$			-0.8
Transition Frequency	f_T	MHz	$I_C=-0.5A, V_{CE}=-5V, f=100MHz$		80	
Output Capacitance	Cob	pF	$V_{CB}=-10V, I_E=0, f=1MHz$			65

■Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
2SB1188B-Q	F2	Approximate 0.055	1000	8000	32000	7" reel

■ Characteristics (Typical)

Fig. 1 - Static Characteristics

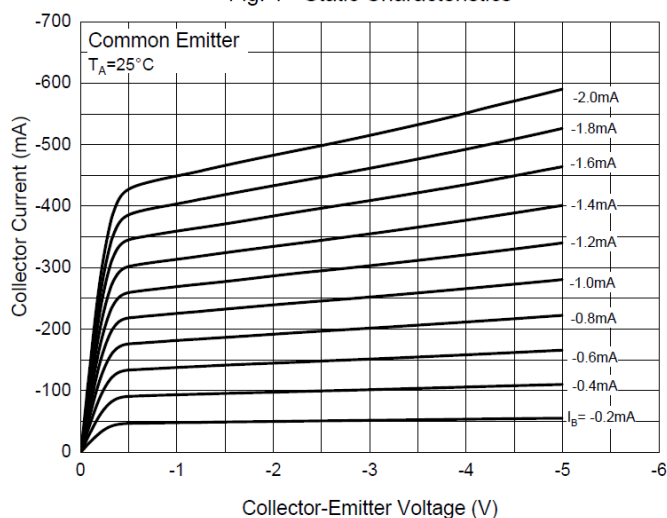


Fig. 2 - DC Current Gain Characteristics

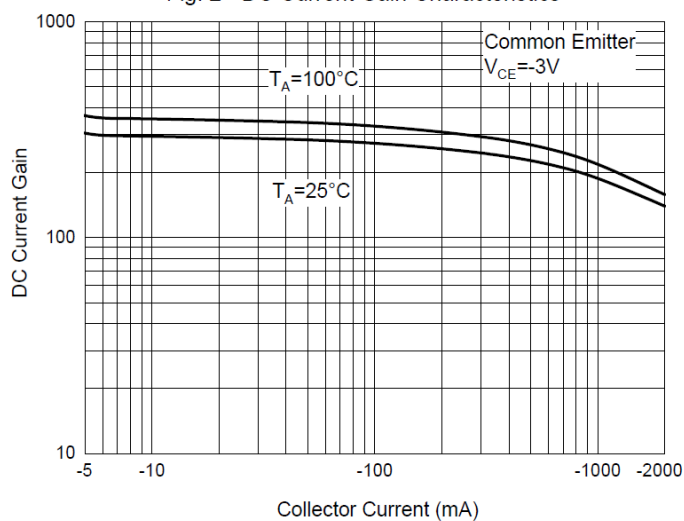


Fig. 3 - Collector-Emitter Saturation Voltage Characteristics

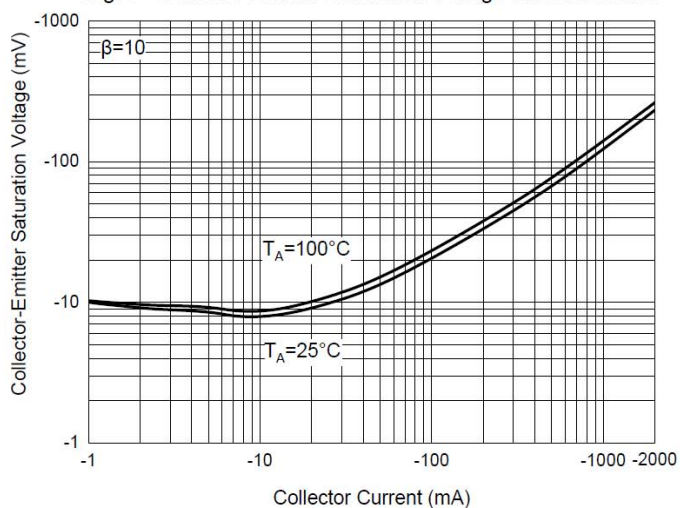


Fig. 4 - Base-Emitter Saturation Voltage Characteristics

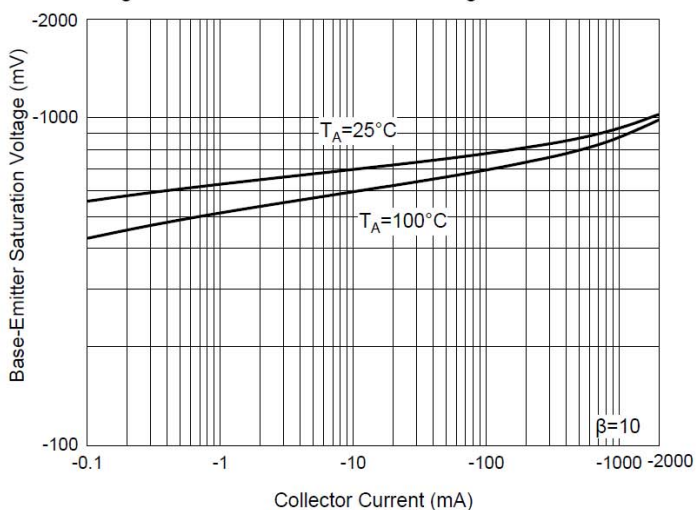


Fig. 5 - Base-Emitter Voltage Characteristics

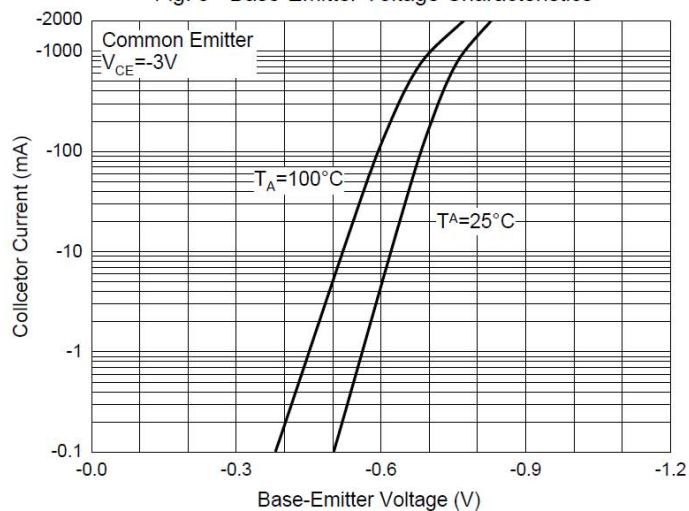
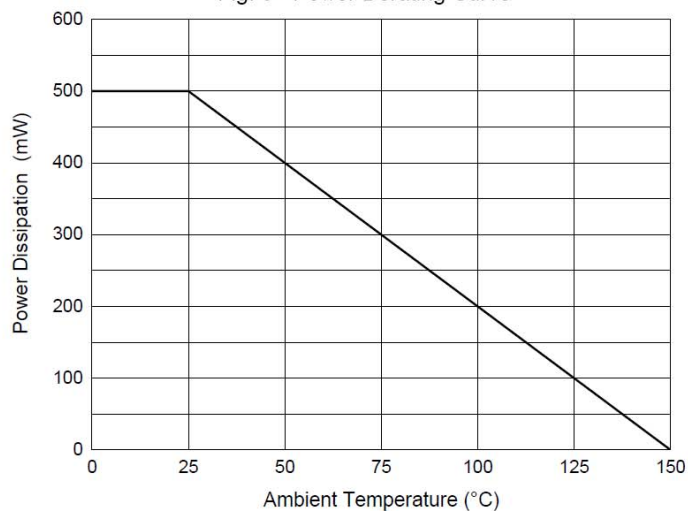


Fig. 6 - Power Derating Curve



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